High-Power Probes

High-voltage/current probes and accessories

DATA SHEET

Cascade Microtech's high-power probes provide a complete on-wafer solution for over-temperature, low-contact resistance measurements of power semiconductors. Together with Tesla on-wafer power device characterization system, Cascade Microtech's high-power probes achieve reliable and repeatable on-wafer measurements up to 300 A and 10,000 V.

Safety Notice: The probes discussed within this data sheet are designed to be used on Cascade Microtech Tesla on-wafer power device characterization systems that incorporate a light curtain, safety interlocks and other features required for the safe use of these types of probes. These probes are only meant to be used on Tesla systems or probing systems that have the same or substantially equivalent safety features. If there is any uncertainty with regard to the safety requirements for your application of these types of products or the safety features of your probing system(s), please consult with your company's safety officials.

| | | H | CP | HVP | | | |
|--------------------------------|-----------------------------|-----------------------|-------------------------------------|-------------------------------|--------------------------|-----------------------------------|--|
| | UHP | HCP-1B | HCP-BNC | HVP-3T | HVP-3C | HVP-13 2 A | |
| Current | Up to 300 A | 100 A | 40 A | 2 A | 5 A | | |
| Voltage | Up to 10,000 V | 500 V | 500 V | 3,000 V (Triax) | 3,000 V (Coax) | 1,500 V (Triax) 3,000 V (Coax) | |
| Typical residual resistance | ≤ 5 mΩ | 10 mΩ | 10 mΩ | 200 mΩ | 30 mΩ | 30 mΩ | |
| Typical probe life | 100,000 touchdowns | 100,000 touchdowns | 100,000 touchdowns | NA | NA | NA | |
| Probe configuration | single, parallel | single, parallel | single | single | single | single | |
| Typical pad material | | | AlSiCu, AlSi, Al, Au* Al, Au* | | AlSiCu, AlSi, Al, Au* | AlSiCu, AlSi, Al, Au* | |
| Connector type | Insulated HV Banana plug | Dual Banana plug | BNC | Coaxial (Agilent HV Triax) | | | |
| Replaceable tip | Yes | Yes | Yes | Yes | Yes | Yes | |
| Configurable tip | Yes | No** | No** | No | No | No | |

HIGH-POWER PROBE SELECTION GUIDE

* Can be used on Au with BeCu Tips.

** Configurable tip available as a special request.



UHP PROBE

Cascade Microtech's Ultra-High-Power Probe (UHP), a high-voltage parametric probe, handles both high voltage (up to 10,000 V) and high current (up to 600 A) at a wide temperature range (-55°C to 300°C). The UHP achieves full I-V characterization with one setup and one touchdown. Together with Tesla on-wafer power device characterization system, the UHP fully utilizes the high-voltage/current capability of Agilent B1505A and N1265A Ultra High Current Expanders.

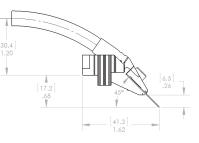
- Coaxial measurements up to 10,000 V and 300 A pulsed (20A DC), without the need for multiple probes and multiple measurement setup changes
- Innovative multi-finger tip design to achieve even distribution of current and minimize pad damage
- Probe current can be doubled up to 600 A when using double probe configuration
- Highly reliable, stable and repeatable measurements with Agilent B1505A and N1265A Ultra High Current Expander

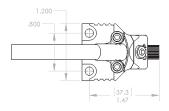
UHP Probe Holder

| Maximum voltage | 10,000 V DC at 200°C, 8,000 V at 300°C | | | | |
|-----------------------------|---|--|--|--|--|
| Maximum current | 300 A pulse (600 A in a parallel configuration) / 20 A DC | | | | |
| Operating temperature range | -55°C to 300°C | | | | |
| Connector type | High-voltage Banana (4 mm) | | | | |
| Length of cable | 1 m | | | | |
| Positioner compatibility | SUMMIT™ RF positioners | | | | |
| Probe residual resistance | $\leq 5 \text{ m}\Omega$ | | | | |
| Probe insulation resistance | > 10 TΩ at 25°C (chuck temperature) | | | | |
| | $> 3 T\Omega$ at 200°C (chuck temperature) | | | | |
| | $> 1 T\Omega$ at 300°C (chuck temperature) | | | | |

Physical Dimensions







UHP Probe Tips

| Typical contact resistance on AlSiCu | | | | | | |
|--------------------------------------|---|------------------------------|--|--|--|--|
| | < 2 m Ω (AlSiCu metal layer) for 12 fingers | | | | | |
| | < 3 m Ω (AlSiCu metal layer) for 8 fingers tip | | | | | |
| | < 6 m Ω (AlSiCu metal layer) for 4 fingers tip | | | | | |
| | < 30 mΩ (AlSiCu me | tal layer) for 1 fingers tip | | | | |
| Tip material | Tungsten | | | | | |
| Recommended range of overtravel | 125-250 μm | | | | | |
| Scrub | ~150 µm (at 300 µm overtravel) | | | | | |
| Finger width | Approximately 250 µm | | | | | |
| Finger pitch | 650 µm | | | | | |
| Probe tip layouts | 12 fingers (300 A) | 7400 µm width | | | | |
| | 8 fingers (200 A) | 4800 µm width | | | | |
| | 4 fingers (100 A) | 2200 µm width | | | | |
| | 1 finger (25 A) | 250 μm width | | | | |
| | | | | | | |

HCP PROBE

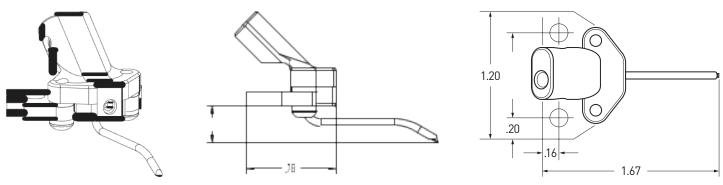
Cascade Microtech's High-Current Probe (HCP) reduces probe and/or device destruction at high currents. It supports 10 A DC and up to 100 A of pulsed current. By design, the probe tip minimizes contact resistance at the wafer-to-probe interface to prevent device heating at the tip. The innovative multi-finger probe tip design distributes current evenly over multiple contact points and is joined by a single heat sink that pulls pull heat from the probe tip.

- Minimal contact resistance at the pad-tip junction to reduce heating during measurements, with fewer probe marks
- Measure devices on wafer at high-current conditions over a wide temperature range (-55°C to 300°C)
- Small scrub minimizes damage on Al pad
- Small footprint tip for small pad probing down to 1 mm x 1 mm pad

HCP Probe Holder

| Maximum voltage | 500 V DC Maximum current (DC) 10 A | |
|-----------------------------|---|--|
| Maximum current (pulse) | 100 A, 1 msec max PW, 1% max duty cycle (BNC: 40 A, 1 msec max PW, 1% max duty cycle) | |
| Total resistance with tip | 10 mΩ (typical) | |
| Operating temperature range | -55°C to 300°C | |
| Isolation resistance | > 100 GΩ at 500 V | |
| Connector type | Dual banana jack or BNC | |
| Length of cable | 1 m (BNC: 0.76 m) | |
| Positioner compatibility | Summit RF positioner | |
| | | |

Physical Dimensions

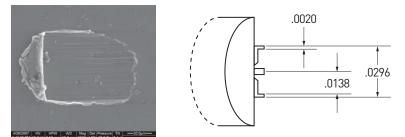


HCP Probe Tips

| Typical contact resistance on Al | 20 mΩ |
|----------------------------------|--|
| Tip material | Tungsten |
| Recommended range of overtravel | 75-125 μm |
| Contact force | 20 grams per tip (60 grams total) at 100 μm overtravel |
| Scrub | 75 µm |

Typical Scrub Mark on Al Pads

The Tesla system HCP probe has been specifically designed for the purpose of minimizing contact resistance, while reducing the amount of probe damage and/or destruction of the device under test. Pictured here is a typical scrub mark on Al pads.



HVP PROBE

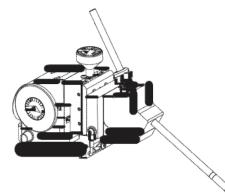
To ensure precision measurements of today's high-voltage devices, Cascade Microtech's High-Voltage Probes (HVP) provide increased isolation resistance and dielectric strength by incorporating advanced internal isolation materials, as well as custom cabling and connectors. When used with Tesla on-wafer characterization system, the HVP assures low-noise electrical performance and full triaxial capability at high voltage without any breakdowns.

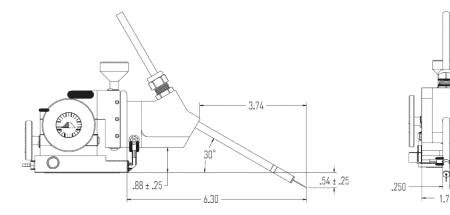
- Accurate coaxial and triaxial measurements up to 10,000 V for a much better understanding of device leakage in the off state
- Highly reliable, stable and repeatable measurements over a wide temperature range (-55°C to 300°C)
- Field-replaceable tips available in a variety of diameters to accommodate device dimensions

HVP Probe Holder

| Maximum voltage guarded (triaxial) | 3,000 V DC |
|--|---|
| Maximum voltage unguarded (coaxial) | 10,000 V DC |
| Maximum current | 5 A pulse / 1 A DC |
| Operating temperature range | -55°C to 300°C |
| Isolation resistance (force to guard) | > 1 TΩ at 3,000 V |
| Typical residual capacitance (with PTT needle) | > 0.5 pF |
| Cable characteristics | Approximately 50 Ω (48 Ω) |
| Connector type | Amphenol triax threaded 11/16-24 , SHV, UHV, or Agilent high-voltage triaxial connector |
| | (connector may limit maximum voltage performance) |
| Replaceable tip type | Straight PTT style needles |
| Recommended range of overtravel | 50 μm to 100 μm |
| Scrub | 20 μm to 40 μm |
| Positioner compatibility | DPP series positioners |
| | |

Physical Dimensions





Typical High-Voltage Triaxial Probe Noise (HVP-3T)*

| | 10 V | | | | 3,000 V | | | | |
|-------------|--------|-------|-------|-------|---------|--------|--------|--------|--|
| Temperature | - 55°C | 25°C | 200°C | 300°C | - 55°C | 25°C | 200°C | 300°C | |
| Noise | 30 fA | 30 fA | 30 fA | 30 fA | 100 fA | 100 fA | 100 fA | 100 fA | |

Typical High-Voltage Coaxial Probe Leakage (HVP-3C)

| | 10 V | | | | 3 ,00 |)0 V | | |
|-------------|---------|---------|---------|---------|----------|----------|---------------|----------|
| Temperature | - 55°C | 25°C | 200°C | 300°C | - 55°C | 25°C | 200°C | 300°C |
| Noise | ≤ 10 pA | ≤ 10 pA | ≤ 10 pA | ≤ 10 pA | ≤ 200 pA | ≤ 200 pA | \leq 200 pA | ≤ 200 pA |

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Data subject to change without notice

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